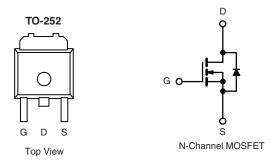
N-Channel 30 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)	Q _g (Typ.)			
30	0.0051 at V _{GS} = 10 V	55 ^d	21.7			
	0.0063 at V_{GS} = 4.5 V	55 ^d	21.7			



FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET ٠
- 100 $\%~R_{q}$ and UIS Tested
- Compliant to RoHS Directive 2002/95/EC ٠

APPLICATIONS

- Power Supply
- Secondary Synchronous Rectification
- DC/DC Converter

ABSOLUTE MAXIMUM RATINGS	T _C = 25 °C, unless oth	erwise noted			
Parameter	-	Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V _{GS}	± 20	- V	
Continuous Drain Current (T ₁ = 150 °C)	T _C = 25 °C		55 ^d		
Continuous Drain Current $(T_j = 150 \text{ C})$	T _C = 70 °C	I _D	55 ^d	_	
Pulsed Drain Current		I _{DM}	100	- A	
Avalanche Current		I _{AS}	40		
Single Avalanche Energy ^a	L = 0.1 mH	E _{AS}	80	mJ	
	T _C = 25 °C	Р	59.5 ^b	14/	
Maximum Power Dissipation ^a	T _A = 25 °C ^c	- P _D -	2.7	- W	
Operating Junction and Storage Temperature Range		T _J , T _{stq}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Limit	Unit		
Junction-to-Ambient (PCB Mount) ^c	R _{thJA}	46	°C/W		
Junction-to-Case (Drain)	R _{thJC}	2.1	0/00		

Notes:

a. Duty cycle \leq 1 %.

b. See SOA curve for voltage derating.c. When mounted on 1" square PCB (FR-4 material).

d. Package limited.



COMPLIANT HALOGEN FREE

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DFG" +@"%

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static		-					
Drain-Source Breakdown Voltage	V _{DS}	$V_{DS} = 0 \text{ V}, \text{ I}_{D} = 250 \mu\text{A}$	30			V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1		2.5	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 250	nA	
		$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$			50	μΑ	
		$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 150 ^{\circ}\text{C}$			250		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 10 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	55			А	
Drain Source On State Desistance		V _{GS} = 10 V, I _D = 22 A		0.0042	0.0051	- Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		0.0052	0.0063		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		110		S	
Dynamic ^b							
Input Capacitance	C _{iss}			2780		pF	
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = 15 V, f = 1 MHz		641			
Reverse Transfer Capacitance	C _{rss}			260			
Total Gate Charge ^c	Qg	$V_{DS} = 15 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		44	66	nC	
Iotal Gate Charge		V _{DS} = 15 V, V _{GS} = 4.5 V, I _D = 20 A		21.7	32.6		
Gate-Source Charge ^c	Q _{gs}			7			
Gate-Drain Charge ^c	Q _{gd}			6.7			
Gate Resistance	R _g	f = 1 MHz	0.4	2	4	Ω	
Turn-On Delay Time ^c	t _{d(on)}			8	16		
Rise Time ^c	t _r	$V_{DD} = 15 \text{ V}, \text{ R}_{L} = 1.5 \Omega$		9	18	-	
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 10$ Å, $V_{GEN} = 10$ V, $R_g = 1$ Ω		35	53	ns	
Fall Time ^c	t _f			9	18		
Drain-Source Body Diode Ratings an	d Characteris	stics $T_C = 25 \ ^{\circ}C^b$			· ·		
Continuous Current	۱ _S				55	۸	
Pulsed Current	I _{SM}				100	A	
Forward Voltage ^a	V _{SD}	I _F = 10 A, V _{GS} = 0 V		0.75	1.5	V	
Reverse Recovery Time	t _{rr}			34	51	ns	
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = 10 A, dl/dt = 100 A/μs		2	3	А	
Reverse Recovery Charge	Q _{rr}			34	51	nC	

Notes:

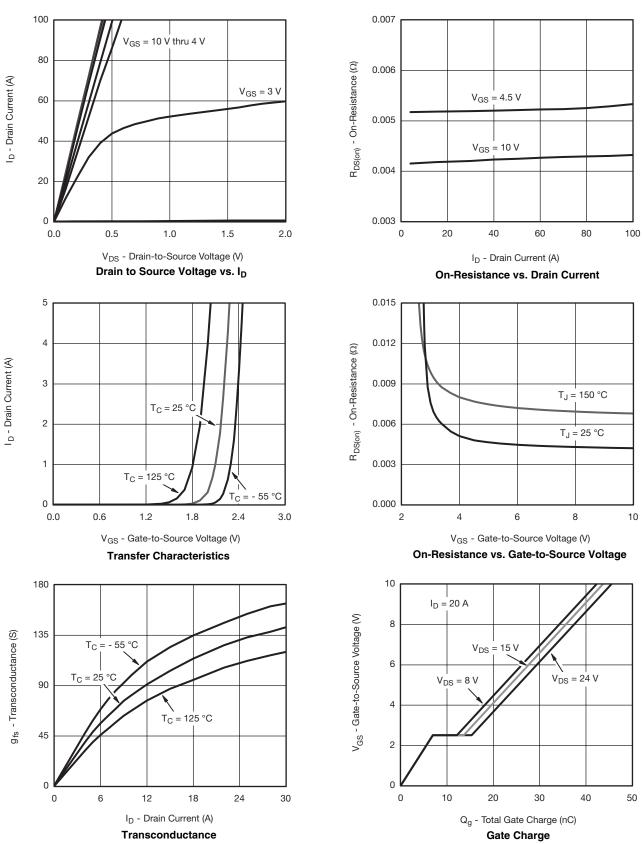
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

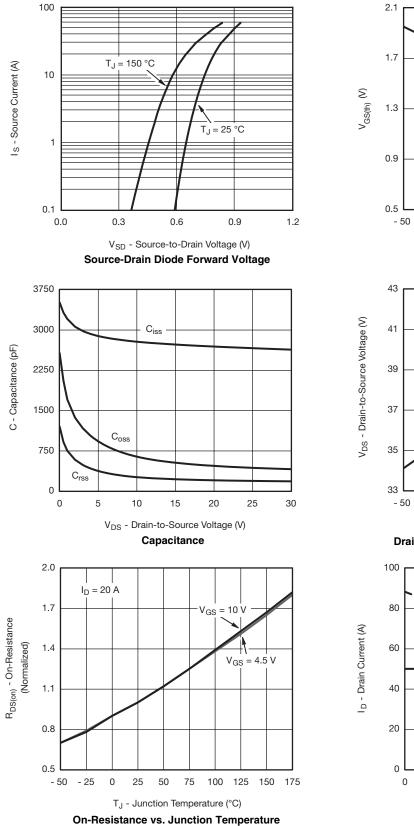
c. Independent of operating temperature.

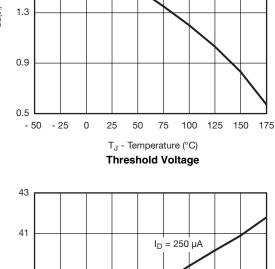
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

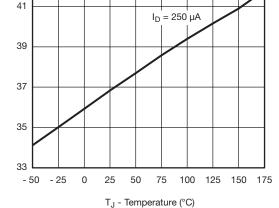


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

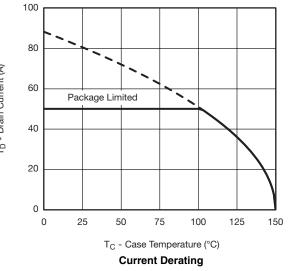




I_D = 250 μA



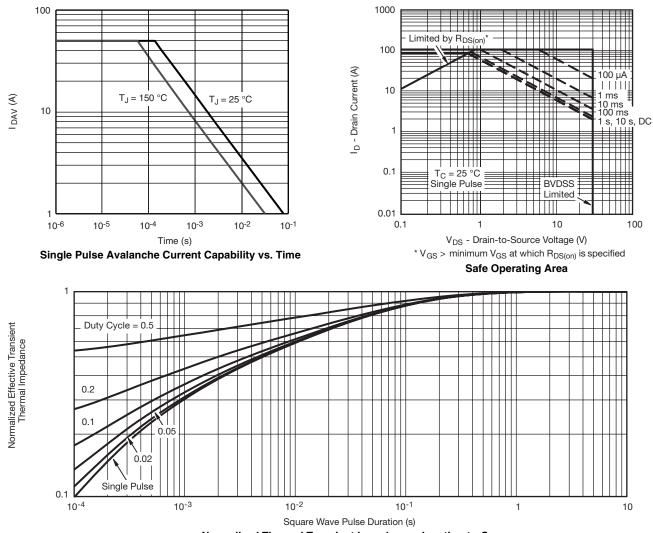
Drain Source Breakdown vs. Junction Temperature



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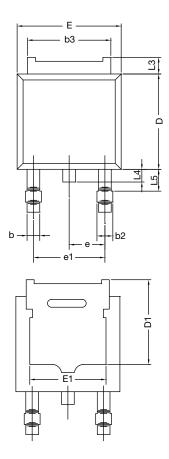
DFG" +@"% www.daysemi.jp

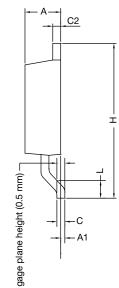
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

TO-252AA CASE OUTLINE





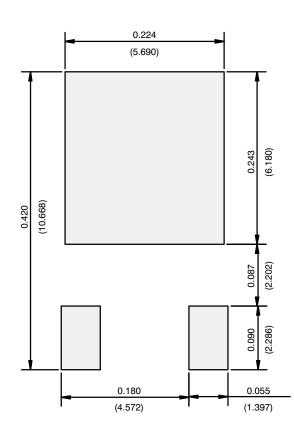
	MILLIN	IETERS	INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	5.21	-	0.205	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28 BSC		0.090 BSC		
e1	4.56 BSC		0.180 BSC		
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	
ECN: X12- DWG: 534	0247-Rev. M, 7	24-Dec-12			

Note

• Dimension L3 is for reference only.

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RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index

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